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July 1999 Revised February 2005

FAIRCHILD

SEMICONDUCTOR®

74VCX132 Low Voltage Quad 2-Input NAND Gate with Schmitt Trigger Inputs and 3.6V Tolerant Inputs and Outputs

General Description

The VCX132 contains four 2-input NAND gates with Schmitt Trigger Inputs. The pin configuration and function are the same as the VCX00 except the inputs have hysteresis between the positive-going and negative-going input thresholds. This hysteresis is useful for transforming slowly switching input signals into sharply defined, jitter-free output signals. This product should be used where noise margin greater than that of conventional gates is required.

The VCX132 is designed for low voltage (1.4V to 3.6V) $V_{\rm CC}$ applications with I/O compatibility up to 3.6V.

This product is fabricated with an advanced CMOS technology to achieve high-speed operation while maintaining low CMOS power dissipation.

Features

- 1.4V to 3.6V V_{CC} supply operation
- 3.6V tolerant inputs and outputs
- t_{PD}
 - 3.3 ns max for 3.0V to 3.6V V_{CC}
- Power-off high impedance inputs and outputs
- Static Drive (I_{OH}/I_{OL}) ±24 mA @ 3.0V V_{CC}
- Uses patented Quiet Series[™] noise/EMI reduction circuitry
- Latchup performance exceeds JEDEC 78 conditions
 ESD performance:
 - Human body model > 2000V
- Machine model > 250V
- Leadless Pb-Free DQFN package

Ordering Code:

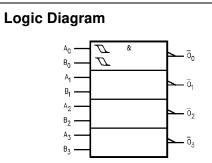
Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow rminal Depopulated Quad Very-Thin Flat Pack No Leads (DQFN), JEDEC						
rminal Depopulated Quad Very-Thin Flat Pack No Leads (DOEN), IEDEC						
3.0mm						
74VCX132MTC MTC14 14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide						

Pb-Free package per JEDEC J-STD-020B.

Note 1: DQFN package available in Tape and Reel only.

Quiet Series[™] is a trademark of Fairchild Semiconductor Corporation.

74VCX132

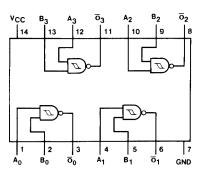


Pin Descriptions

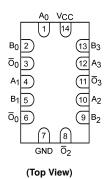
Pin Name	Description
A _n , B _n	Inputs
Ōn	Outputs

Connection Diagrams

Pin Assignments for SOIC and TSSOP



Pad Assignments for DQFN



Absolute Maximum Ratings(Note 2)		Recommended Operating		
Supply Voltage (V _{CC})	-0.5V to +4.6V	Conditions (Note 4)		
DC Input Voltage (VI)	-0.5V to 4.6V	Power Supply		
DC Output Voltage (V _O)		Operating	1.4V to 3.6V	
HIGH or LOW State (Note 3)	–0.5V to V _{CC} + 0.5V	Input Voltage	-0.3V to 3.6V	
$V_{CC} = 0V$	-0.5V to +4.6V	Output Voltage (V _O)		
DC Input Diode Current (I _{IK})		HIGH or LOW State	0V to V _{CC}	
$V_{I} < 0V$	–50 mA	Output Current in I _{OH} /I _{OL}		
DC Output Diode Current (I _{OK})		V _{CC} = 3.0V to 3.6V	±24 mA	
$V_{O} < 0V$	–50 mA	V _{CC} = 2.3V to 2.7V	±18 mA	
$V_{O} > V_{CC}$	+50 mA	V _{CC} = 1.65V to 2.3V	±6 mA	
DC Output Source/Sink Current		V _{CC} = 1.4V to 1.6V	±2 mA	
(I _{OH} /I _{OL})	±50 mA	Free Air Operating Temperature (T _A)	-40°C to +85°C	
DC V _{CC} or Ground Current per				
Supply Pin (I _{CC} or Ground)	±100 mA	Note 2: The "Absolute Maximum Ratings" are those		
Storage Temperature (T _{STG})	–65°C to +150°C	PC the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.		

Note 3: I_O Absolute Maximum Rating must be observed. Note 4: Floating or unused inputs must be held HIGH or LOW.

DC Electrical Characteristics

Symbol	Parameter	Conditions	V _{CC} (V)	Min	Max	Units
V _{t+}	HIGH Level Input Voltage		3.6		2.2	
			3.0		2.0	
			2.3		1.6	v
			1.6		1.2	
			1.4		1.2	
V _{t-}	LOW Level Input Voltage		3.6	0.8		
			3.0	0.7		
			2.3	0.5		V
			1.6	0.2		
			1.4	0.2		
V _H	Input Hysteresis		3.6	0.3	1.2	
			3.0	0.3	1.2	
			2.3	0.3	1.0	V
			1.6	0.15	0.9	
			1.4	0.15	0.9	
V _{OH}	HIGH Level Output Voltage	I _{OH} = -100 μA	2.7 - 3.6	V _{CC} - 0.2		
		I _{OH} = -12 mA	2.7	2.2		
		I _{OH} = -18 mA	3.0	2.4		
		$I_{OH} = -24mA$	3.0	2.2		
		$I_{OH} = -100 \ \mu A$	2.3 - 2.7	V _{CC} - 0.2		İ
		I _{OH} = -6 mA	2.3	2.0		v
		$I_{OH} = -12 \text{ mA}$	2.3	1.8		v
		I _{OH} = -18 mA	2.3	1.7		
		$I_{OH} = -100 \ \mu A$	1.65 - 2.3	V _{CC} - 0.2		İ
		$I_{OH} = -6 \text{ mA}$	1.65	1.25		
		$I_{OH} = -100 \mu A$	1.4 - 1.6	V _{CC} - 0.2		1
		I _{OH} = -2 mA	1.4	1.05		

74VCX132

74VCX132

DC Electrical Characteristics (Continued)

Symbol	Parameter	Conditions	V _{CC} (V)	Min	Max	Units
V _{OL}	LOW Level Output Voltage	I _{OL} = 100 μA	2.7 - 3.6		0.2	
		$I_{OL} = 12 \ \mu A$	2.7		0.4	
		I _{OL} = 18 mA	3.0		0.4	
		$I_{OL} = 24 \text{ mA}$	3.0		0.55	
		$I_{OL} = 100 \ \mu A$	2.3 - 2.7		0.2	
		$I_{OL} = 12 \text{ mA}$	2.3		0.4	V
		I _{OL} = 18 mA	2.3		0.6	
		$I_{OL} = 100 \ \mu A$	1.65 - 2.3		0.2	
		$I_{OL} = 6 \text{ mA}$	1.65		0.3	
		$I_{OL} = 100 \ \mu A$	1.4 - 1.6		0.2	
		$I_{OL} = 2 \text{ mA}$	1.4		0.35	
I	Input Leakage Current	$0 \le V_I \le 3.6V$	1.4 - 3.6		±5.0	μA
oz	3-STATE Output Leakage	$0 \le V_O \le 3.6V$	1.4 - 3.6		±10.0	
		$V_I = V_{IH} \text{ or } V_{IL}$	1.4 - 3.0		±10.0	μΑ
OFF	Power Off Leakage Current	$0 \leq (V_I, V_O) \leq 3.6 V$	0		10.0	μA
сс	Quiescent Supply Current	$V_I = V_{CC}$ or GND	1.4 - 3.6		20.0	
		$V_{CC} \leq V_I \leq 3.6 V$	1.4 - 3.6		±20.0	μA
7I ^{CC}	Increase in I _{CC} per Input	$V_{IH} = V_{CC} - 0.6V$	2.7 - 3.6		750	μA

AC Electrical Characteristics (Note 5)

Symbol	Parameter	Conditions	V _{cc}	$T_A = -40^{\circ}$	C to +85°C	Units	Figure
	Faranieler	conditions	(V)	Min	Max	Units	Number
t _{PHL}	Propagation Delay	$C_L = 30 \text{ pF}, \text{ R}_L = 500 \Omega$	$\textbf{3.3}\pm\textbf{0.3}$	0.6	3.3		_
t _{PLH}			$\textbf{2.5}\pm\textbf{0.2}$	0.8	4.1		Figures 1, 2
			1.8 ± 0.15	1.0	8.2	ns	., _
		$C_L = 15 \text{ pF}, \text{ R}_L = 2 k \Omega$	1.5 ± 0.1	1.0	16.4		Figures 3, 4
t _{OSHL}	Output-to-Output Skew	$C_L = 30 \text{ pF}, \text{ R}_L = 500 \Omega$	$\textbf{3.3}\pm\textbf{0.3}$		0.5		
t _{OSLH}	(Note 6)		$\textbf{2.5}\pm\textbf{0.2}$		0.5	ns	
			1.8 ± 0.15		0.75	115	
		$C_L = 15 \text{ pF}, \text{ R}_L = 2k\Omega$	1.5 ± 0.1		1.5		

Note 5: For C_L = 50 pF, add approximately 300 ps to the AC maximum specification.

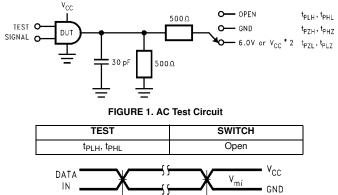
Note 6: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

Symbol	Parameter	Conditions	V _{CC} T	$T_A = +25^{\circ}C$	Units
Symbol	Faranieter	Conditions	(V)	Typical	Units
V _{OLP}	Quiet Output Dynamic Peak V _{OL}	$C_L = 30 \text{ pF}, \text{ V}_{IH} = \text{ V}_{CC}, \text{ V}_{IL} = 0\text{V}$	1.8	0.25	
			2.5	0.6	V
			3.3	0.8	
V _{OLV}	Quiet Output Dynamic Valley V _{OL}	$C_L = 30 \text{ pF}, \text{ V}_{IH} = \text{ V}_{CC}, \text{ V}_{IL} = 0\text{V}$	1.8	-0.25	
			2.5	-0.6	V
			3.3	-0.8	
V _{OHV}	Quiet Output Dynamic Valley V _{OH}	$C_L = 30 \text{ pF}, V_{IH} = V_{CC}, V_{IL} = 0V$	1.8	1.5	
			2.5	1.9	V
			3.3	2.2	

Capacitance

Symbol	Parameter Conditions		$T_A = +25^{\circ}C$	Units
Cymbol	i arameter	Conditions	Typical	onito
C _{IN}	Input Capacitance	$V_{I} = 0V \text{ or } V_{CC}, V_{CC} = 1.8V, 2.5V \text{ or } 3.3V$	6.0	pF
COUT	Output Capacitance	$V_I = 0V \text{ or } V_{CC}, V_{CC} = 1.8V, 2.5V \text{ or } 3.3V$	7.0	pF
C _{PD}	Power Dissipation Capacitance	$V_{I} = 0V \text{ or } V_{CC}, f = 10MHz, V_{CC} = 1.8V, 2.5V \text{ or } 3.3V$	20.0	pF

AC Loading and Waveforms (V_{CC} 3.3V \pm 0.3V to 1.8V \pm 0.15V)



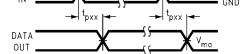
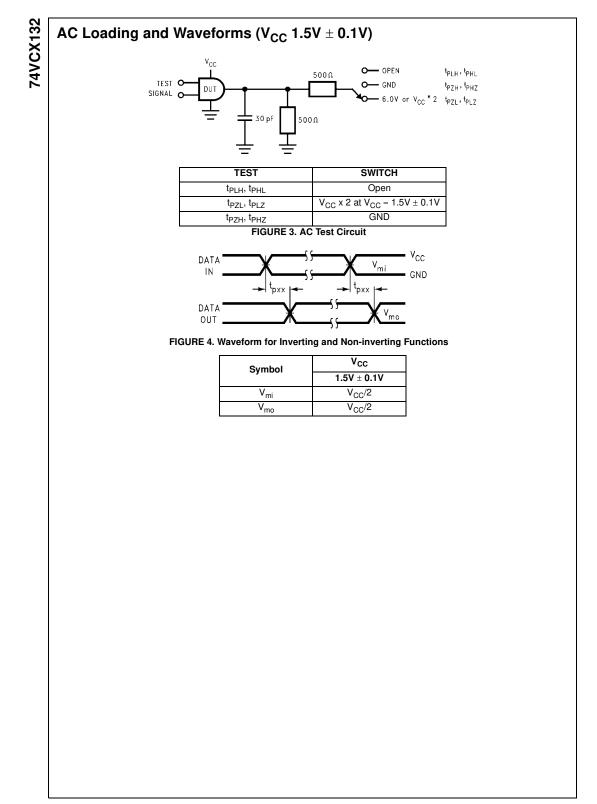
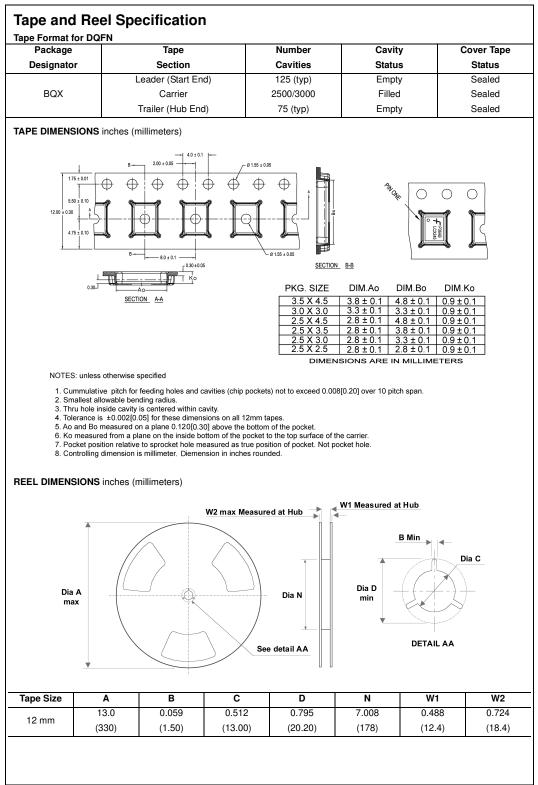


FIGURE 2. Waveform for Inverting and Non-inverting Functions

Symbol		v _{cc}	
e y iniser	$3.3V \pm 0.3V$	$2.5V \pm 0.2V$	1.8V ± 0.15V
V _{mi}	1.5V	V _{CC} /2	V _{CC} /2
V _{mo}	1.5V	V _{CC} /2	V _{CC} /2





74VCX132

